

### Day 1 - Tuesday 8th April 2025

08:00 Registration and welcome refreshments

08:50 Housekeeping by Chris Meadows and Tim Bettles - Conference Chairs

#### GaN: Going beyond fast charging

Achieving Avalanche in GaN-on-silicon Diodes 09:00 Presented by Farid Medjdoub - University of Lille

Presentation by Yole Group 09:15

Presented by Name to be advised - Yole Group

Harnessing the Underestimated Potential of GaN in the Digitalization Revolution: A Catalyst for Unforeseen Innovation in

09:30 **Energy Efficiency** 

Presented by Roberto Crisafulli - ST Microelectronics

09:45 Presentation Title to be Confirmed 10:00 Presentation Title to be Confirmed 10:15 Presentation Title to be Confirmed

10:30 Morning Break

11:10 Presentation Title to be Confirmed 11:25 Presentation Title to be Confirmed 11:40 Presentation Title to be Confirmed 11:55 Presentation Title to be Confirmed 12:10 Presentation Title to be Confirmed

Lunch Break 12:25

#### Expanding the emission envelope

**Expanding the Spectral Range of GaN-based SLEDs** 13:55

Presented by Marco Malinverni - Exalos

Perfecting GaN VCSEL Production Process 14:10

Presented by Tetsuya Takeuchi - Meijo University

The Power of Pseudomorphic Nitrides 14:25

Presented by Leo Schowalter - Lit Thinking

Presentation by Umicore 14:40

Presented by Name to be advised - Umicore

14:55 Presentation Title to be Confirmed

15:10 Afternoon Break

#### Maintaining momentum for the microLED

Perfecting the Polychromatic Pixel 15:50 Presented by Michelle Chen - Q-Pixel Inc

MicroSolid Printing: Redefining the Future of MicroLED Displays 16:05

Presented by Reza Chaji - Vue Real

Presentation by Yole Group 16:20

Presented by Name to be advised - Yole Group

Pioneering Mass Production and Commercialisation of MicroLED Microdisplays for AR 16:35

Presented by Tongtong Zhu - Porotech

Revolutionising microLED displays with nanowires 16:50

Presented by Pierre Tchoulfian - Aledia

17:05 Presentation Title to be Confirmed

**Closing Remarks** 

17:20

18:00 **Networking Drinks / Dinner Reception** 

## Day 2 - Wednesday 9th April 2025

Registration and welcome refreshments

08:00

08:50	Housekeeping by Chris Meadows and Tim Bettles - Conference Chairs	
Ultra-w	ide bandgap materials: The ultimate devices	Sponsored by Precision Fabricators
09:00	Prospects of (ultra) Wide Bandgap Oxide ICs  Presented by Xiaohang Li - KAUST	
09:15	A Solution to Doping AlN Presented by Alan Doolittle - Georgia Institute of Technology	
09:30	Electric Field Engineering to Unlock the Potential of Gallium Oxide Power Devices  Presented by Nolan Hendricks - AFRL (Air Force Research Laboratory)	
09:45	Efficient Diameter Enlargement of Bulk AlN Presented by Carsten Hartmann - Leibniz-Institut für Kristallzüchtung (IKZ)	
10:00	The Promise of Cubic BN  Presented by Siddha Pimputkar - Lehigh University	
10:15	Morning Break	
10:55	Expanding the Ultra-Wide Bandgap Portfolio with Transition Metal Nitrides: AlScN and AlYN Presented by Stefano Leone - Fraunhofer Institute IAF	1
11:10	Presentation by EV Group  Presented by Dr. Bernd Dielacher - EV Group	
11:25	Presentation Title to be Confirmed	
11:40	Presentation Title to be Confirmed	
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11:55	Presentation Title to be Confirmed	
12:10	Lunch Break	
12:10		
12:10	Lunch Break	
12:10 Optimis	Lunch Break sing opportunities for SiC success The Merits of the Merged p-i-n SiC Schottky Diode	
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# **NOTES**